

03599.000081



PATENT APPLICATION

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:)
SHINZO UCHIYAMA) Examiner: Not Yet Assigned
Application No.: 10/699883) Group Art Unit: NYA
Filed: November 4, 2003)
For: PROCESS FOR PRODUCING)
A SEMICONDUCTOR)
DEVICE) January 6, 2004

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

INFORMATION DISCLOSURE STATEMENT

Sir:

In compliance with the duty of disclosure under 37 C.F.R. § 1.56 and in accordance with the practice under 37 C.F.R. §§ 1.97 and 1.98, the Examiner's attention is directed to the documents listed on the enclosed Form PTO-1449. Copies of the listed foreign documents are also enclosed.

The concise explanation of relevance for the non-English documents is found in the specification where cited, in a corresponding U.S. Patent No. 6,497,783 for JPLO 2925535 and in translations of Preprints for Japan Soc. of Appl. Physics.

CONCLUSION

It is respectfully requested that the above information be considered by the Examiner and that a copy of the enclosed Form PTO-1449 be returned indicating that such information has been considered.

Applicant's undersigned attorney may be reached in our New York office by telephone at (212) 218-2100. All correspondence should continue to be directed to our address given below.

Respectfully submitted,



Attorney for Applicant
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U.S. DEPARTMENT OF COMMERCE
PATENT AND TRADEMARK OFFICE
LIST OF REFERENCES CITED BY APPLICANT(S)
(Use several sheets if necessary)

ATTY DOCKET NO.
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APPLICATION NO.
10/699883

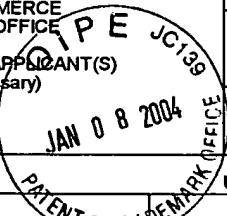
APPLICANT

SHINZO UCHIYAMA

FILING DATE

November 4, 2003

GROUP

UNASSIGNED

U.S. PATENT DOCUMENTS

*EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
	5753320	5/98	Mikoshiba, et al.	427	572	
	6217704	3/01	Kitagawa	156	345	
	6410450	6/02	Kitagawa	438	710	
	6426302	7/02	Kitigawa	438	710	
	6497783	12/02	Suzuki, et al.	156	345	5/98

FOREIGN PATENT DOCUMENTS

	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION YES/NO/ OR ABSTRACT
JP	2925535	5/99	JAPAN			

OTHER DOCUMENT(S) (Including Author, Title, Date, Pertinent Pages, Etc.)

	Sasada, et al.; "Low Temperature Formation Activated Oxygen/Nitrogen"; 62nd Japan Soc. Appl. Phys., Annual Meeting Preprint No. 2, page 631, 12a-C-10 (2001)
	Aria, et al.; "The origin of the increase silicon oxide"; 62nd Japan Soc. Appl. Phys., Annual Meeting Preprint No. 2, page 630, 12a-C-9 (2001)

EXAMINER

DATE CONSIDERED

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.